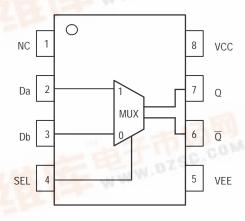
2:1 Multiplexer

The MC100LVEL58 is a 2:1 multiplexer. The device is pin and functionally equivalent to the EL58 and works from a -3.3V supply. With AC performance similar to the EL58 device, the LVEL58 is ideal for low voltage applications which require the ultimate in AC performance.

- 440ps Typical Propagation Delays
- High Bandwidth Output Transitions
- PECL mode: 3.0V to 5.5V V_{CC} with V_{EE} = 0V
- ECL mode: $0V V_{CC}$ with $V_{EE} = -3.0V$ to -5.5V
- 75kΩ Internal Input Pulldown Resistors
- >4000V ESD Protection
- Moisture Sensitivity Level 1, Indefinite Time Out of Drypack For Additional Information, See Application Note AND8003/D
- Flammability Rating: UL-94 code V-0 @ 1/8", Oxygen Index 28 to 34
- Transistor Count: 729 devices

Logic Diagram and Pinout: 8-Lead SOIC (Top View)





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MARKING DIAGRAM*



A = Assembly Location

L = Wafer Lot

Y = Year

W = Work Week

PIN NAMES

Pins	Function
Da, Db Q	Data Inputs Data Outputs

TRUTH TABLE

SEL	Data
H	a GOW

ORDERING INFORMATION

Device	Package	Shipping				
MC100LVEL58D	SO-8	98 Units / Rail				
MC100LVEL58DR2	SO-8	2500 Units / Reel				



^{*}For additional information, see Application Note WWW.DZSC.COM AND8002/D

ABSOLUTE MAXIMUM RATINGS¹

Symbol	Characteristic	Rating	Unit	
VEE	Power Supply (V _{CC} = 0V)		-8.0 to 0	VDC
٧ _I	Input Voltage (V _{CC} = 0V)		0 to -6.0	VDC
l _{out}	Output Current Continuous Surge		50 100	mA
TA	Operating Temperature Range		-40 to +85	°C
VEE	Operating Range ^{1,2}		−5.7 to −3.0	V
θЈА	Thermal Resistance (Junction-to-Ambient)	Still Air 500lfpm	190 130	°C/W
θЈС	Thermal Resistance (Junction-to-Case)		41 to 44 ± 5%	°C/W
T _{sol}	Solder Temperature (<2 to 3 Seconds: 245°C desired)		265	°C

- Absolute maximum rating, beyond which, device life may be impaired, unless otherwise specified on an individual data sheet.
 Parametric values specified at: 100EL Series: -4.20V to -5.50V
- 2. Parametric values specified at: 10EL Series: -4.94V to -5.50V

MC100LVEL58

DC CHARACTERISTICS (VEE = VEE(min) to VEE(max); VCC = GND)

			–40°C			0°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
IEE	Power Supply Current		21	28		21	28		21	28		23	30	mA
VEE	Power Supply Voltage	3.0		3.8	3.0		3.8	3.0		3.8	3.0		3.8	V
liH	Input HIGH Current			150			150			150			150	μΑ

MC100LVEL58

AC CHARACTERISTICS (VEE = VEE(min) to VEE(max); V_{CC} = GND)

			-40°C			0°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Unit									
t _{PLH}	Propagation D Q Delay SEL Q	340 350	435 455	560 570	340 350	435 455	560 570	350 360	440 460	570 580	370 380	450 470	590 600	ps
t _r t _f	Output Rise/Fall Times Q (20% – 80%)	100		320	100		320	100		320	100		320	ps

DC CHARACTERISTICS

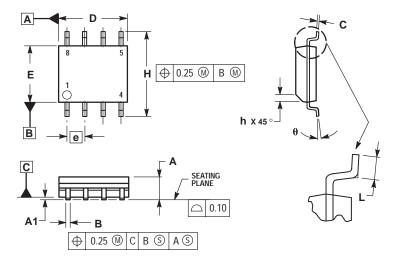
(VEE = VEE(min) - VEE(max); VCC = GND1), All input and output voltage parameters vary 1:1 with VCC

		–40°C			C)°C to 85°C	;		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Unit	Condition
VOH	Output HIGH Voltage(2)	-1085	-1005	-880	-1025	-955	-880	mV	$V_{IN} = V_{IH}(max)$
V _{OL}	Output LOW Voltage(2)	-1830	-1695	-1555	-1810	-1705	-1620	mV	or V _{IL} (min)
VOHA	Output HIGH Voltage(2)	-1095	_	_	-1035	_	_	mV	V _{IN} = V _{IH} (max)
V _{OLA}	Output LOW Voltage(2)	_	_	-1555	_	_	-1610	mV	or V _{IL} (min)
VIH	Input HIGH Voltage	-1165	_	-880	-1165	_	-880	mV	
VIL	Input LOW Voltage	-1810		-1475	-1810	_	-1475	mV	
I _{IL}	Input LOW Current	0.5	_	_	0.5	_	_	μΑ	$V_{IN} = V_{IL}(max)$

- V_{CC} = 0V, V_{EE} = V_{EEmin} to V_{EEmax}, all other pins floating.
 All loading with 50 ohms to V_{CC}-2.0 volts.

PACKAGE DIMENSIONS

SO-8 **D SUFFIX** CASE 751-06 ISSUE T



NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

2. DIMENSIONS ARE IN MILLIMETER.

3. DIMENSION D AND E DO NOT INCLUDE MOLD PROTRUSION.

4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.

5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETER							
DIM	MIN	MAX						
Α	1.35	1.7						
A1	0.10	0.2						
В	0.35	0.49						
С	0.19	0.2						
D	4.80	5.00						
Ε	3.80	4.00						
е	1.27	BSC						
Н	5.80	6.20						
h	0.25	0.50						
L	0.40	1.2						
θ	0 °	7						

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